



500V/3A Switching Regulator Applications

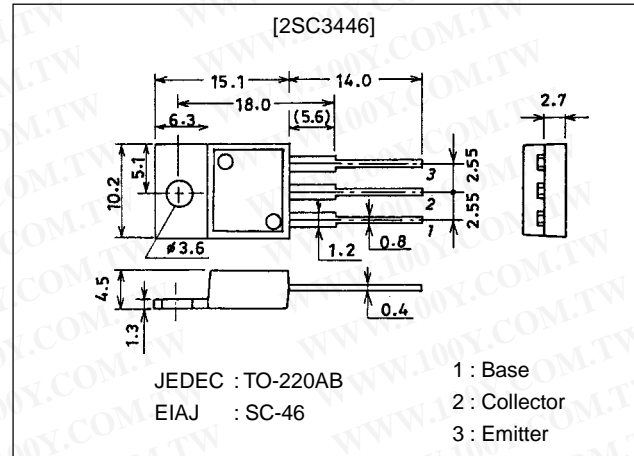
Features

- High breakdown voltage and high reliability.
- Fast switching speed (t_f : 0.1 μ s typ).
- Wide ASO.
- Adoption of MBIT process.

勝特力材料 886-3-5753170
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Package Dimensions

unit:mm
2010C



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		800	V
Collector-to-Emitter Voltage	V_{CEO}		500	V
Emitter-to-Base Voltage	V_{EBO}		7	V
Collector Current	I_C		3	A
Collector Current (Pulse)	I_{CP}	$PW \leq 300\mu s, Duty\ Cycle \leq 10\%$	6	A
Base Current	I_B		1	A
Collector Dissipation	P_C	$T_c = 25^\circ C$	40	W
Junction Temperature	T_j		150	$^\circ C$
Storage Temperature	T_{stg}		-55 to +150	$^\circ C$

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = 500V, I_E = 0$			10	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = 5V, I_C = 0$			10	μA
DC Current Gain	h_{FE1}	$V_{CE} = 5V, I_C = 0.3A$	15*			
	h_{FE2}	$V_{CE} = 5V, I_C = 1.5A$	8			
Gain-Bandwidth Product	f_T	$V_{CE} = 10V, I_C = 0.3A$		18		MHz
Output Capacitance	C_{ob}	$V_{CB} = 10V, f = 1MHz$		50		pF

* : The h_{FE1} of the 2SC3446 is classified as follows. When specifying the h_{FE1} rank, specify two ranks or more in principle.

15	L	30	20	M	40	30	N	50
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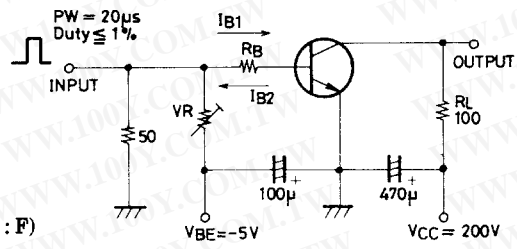
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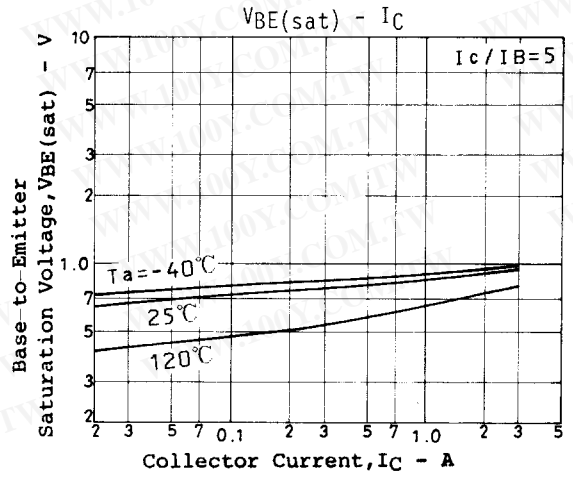
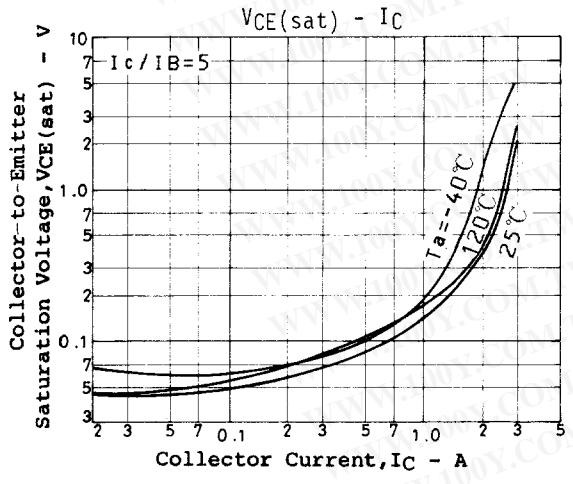
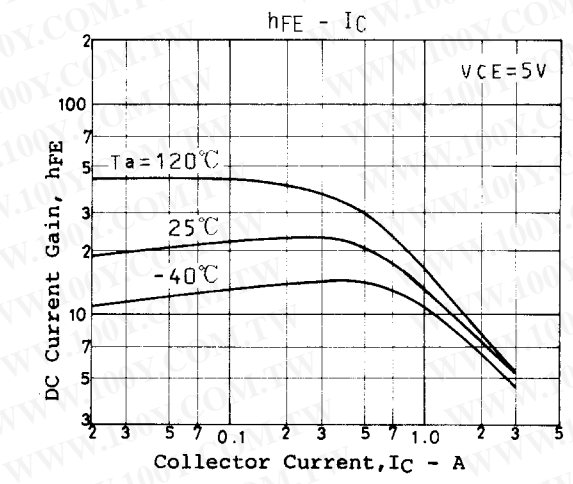
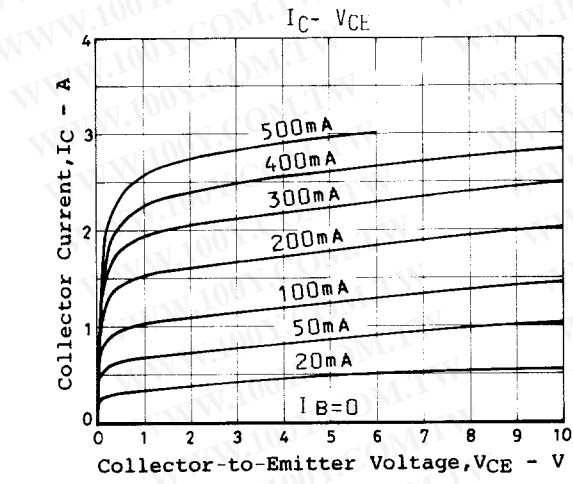
2SC3446

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=1.5A, I_B=0.3A$			1.0	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=1.5A, I_B=0.3A$			1.5	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=1mA, I_E=0$	800			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=5mA, R_{BE}=\infty$	500			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=1mA, I_C=0$	7			V
Collector-to-Emitter Sustain Voltage	$V_{CEX(sus)}$	$I_C=1.5A, I_{B1}=-I_{B2}=0.6A, L=2mH, \text{clamped}$	500			V
Turn-ON Time	t_{on}	$V_{CC}=200V, 5I_{B1}=-2.5I_{B2}=I_C=2A, R_L=100\Omega$			0.5	μs
Storage Time	t_{stg}	$V_{CC}=200V, 5I_{B1}=-2.5I_{B2}=I_C=2A, R_L=100\Omega$			3.0	μs
Fall Time	t_f	$V_{CC}=200V, 5I_{B1}=-2.5I_{B2}=I_C=2A, R_L=100\Omega$			0.3	μs

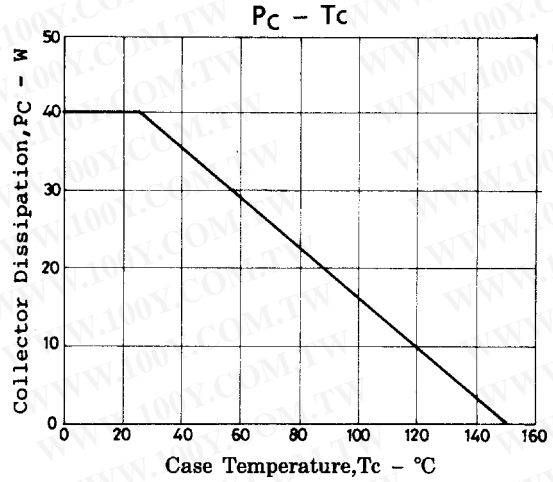
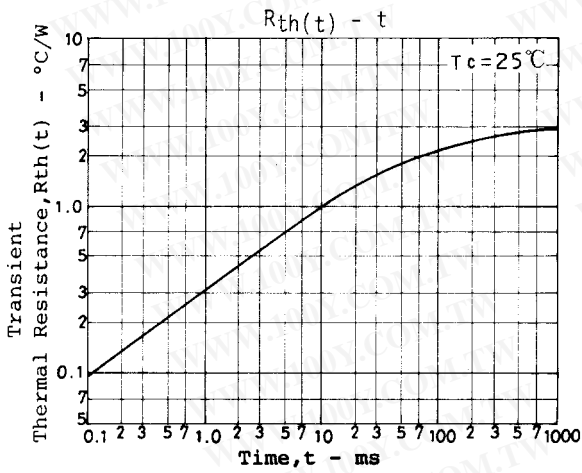
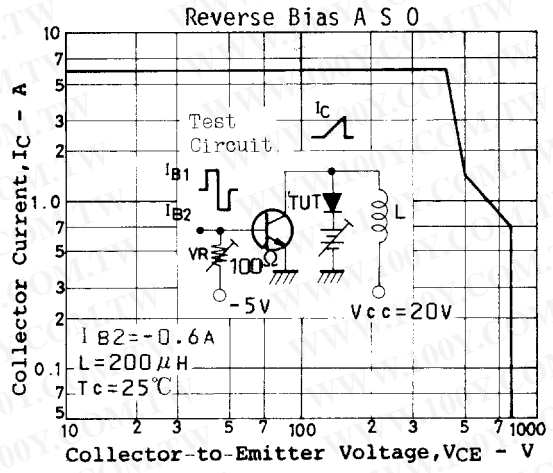
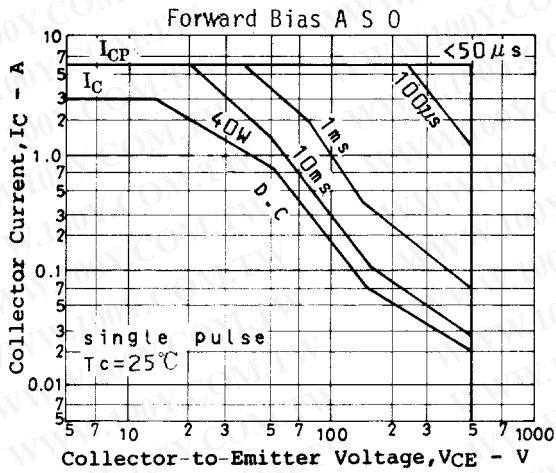
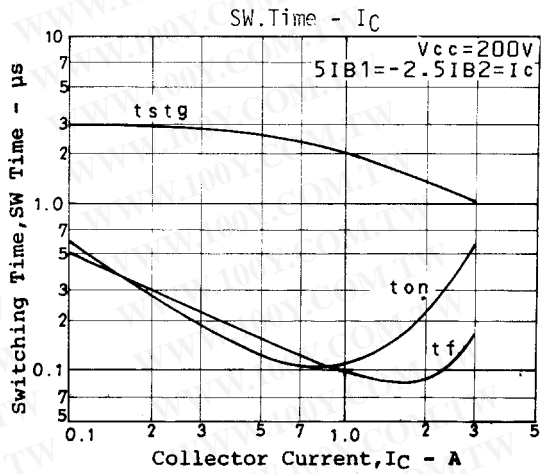
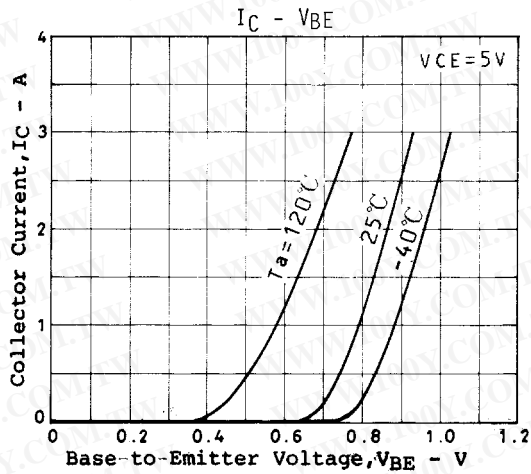
Switching Time Test Circuit



Unit (resistance : Ω, capacitance : F)



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